Bus Buffer with 3-State Output
NL17SG125

The NL17SG125 MiniGate™ is an advanced high−speed CMOS Bus Buffer with 3−State Output in ultra−small footprint.

The NL17SG125 input structures provides protection when voltages up to 3.6 V are applied.

Features

- Wide Operating V_{CC} Range: 0.9 V to 3.6 V
- High Speed: t_{PD} = 2.4 ns (Typ) at V_{CC} = 3.0 V, C_L = 15 pF
- Low Power Dissipation: I_{CC} = 0.5 μA (Max) at T_A = 25°C
- 3.6 V Overvoltage Tolerant (OVT) Input Pins
- I_{OFF} Supports Partial Power Down Protection
- Ultra−Small Packages
- −Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q100 Qualified and PPAP Capable
- These Devices are Pb−Free, Halogen Free and are RoHS Compliant

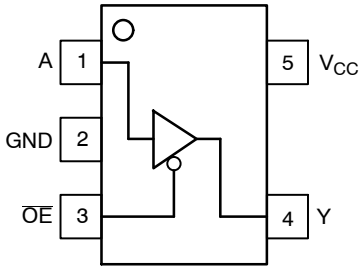


Figure 1. SOT−953
(Top Thru View)

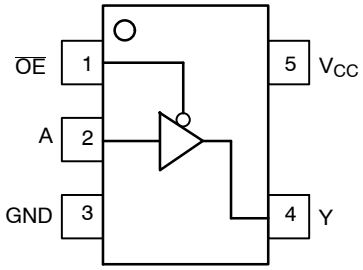


Figure 2. SC−88A
(Top View)

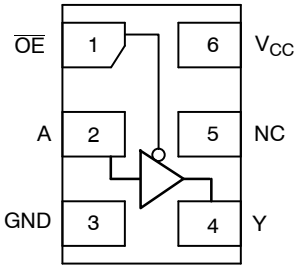


Figure 3. UDFN6
(Top View)

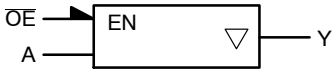
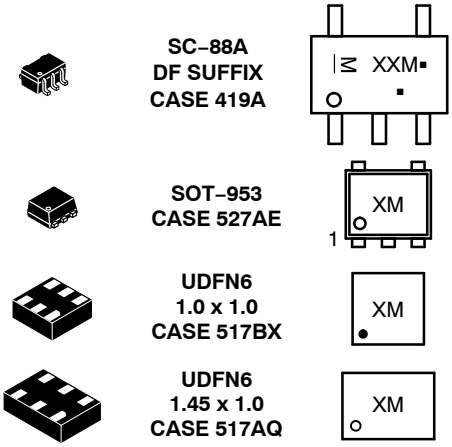


Figure 4. Logic Symbol

PIN ASSIGNMENT

Pin Number	SOT−953	SC−88A	UDFN6
1	A	$\overline{OE}$	$\overline{OE}$
2	GND	A	A
3	$\overline{OE}$	GND	GND
4	Y	Y	Y
5	V_{CC}	V_{CC}	NC
6			V_{CC}

MARKING DIAGRAMS



XX = Specific Device Code
M = Date Code*
▪ = Pb−Free Package

(Note: Microdot may be in either location)
*Date Code orientation and/or position may vary depending upon manufacturing location.

FUNCTION TABLE

A Input	$\overline{OE}$ Input	Y Output
L	L	L
H	L	H
X	H	Z

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

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Table 1. MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V_{CC}	DC Supply Voltage		−0.5 to +4.3	V
V_{IN}	DC Input Voltage		−0.5 to +4.3	V
V_{OUT}	DC Output Voltage	Active−Mode (High or Low State) Tri−State Mode (Note 1) Power−Down Mode (V_{CC} = 0 V)	−0.5 to V_{CC} + 0.5 −0.5 to +4.3 −0.5 to +4.3	V
I_{IK}	DC Input Diode Current	V_{IN} < GND	−20	mA
I_{OK}	DC Output Diode Current	V_{OUT} < GND	−20	mA
I_{OUT}	DC Output Source/Sink Current		±20	mA
I_{CC} or I_{GND}	DC Supply Current Per Supply Pin or Ground Pin		±20	mA
T_{STG}	Storage Temperature Range		−65 to +150	°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds		260	°C
T_J	Junction Temperature Under Bias		+150	°C
θ_{JA}	Thermal Resistance (Note 2)	SC−88A SOT−953 UDFN6	377 254 154	°C/W
P_D	Power Dissipation in Still Air at 85°C	SC−88A SOT−953 UDFN6	332 491 812	mW
MSL	Moisture Sensitivity		Level 1	
F_R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V−0 @ 0.125 in	
V_{ESD}	ESD Withstand Voltage (Note 3)	Human Body Model Charged Device Model	2000 1000	V
$I_{LATCHUP}$	Latchup Performance (Note 4)		±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Applicable to devices with outputs that may be tri−stated.
2. Measured with minimum pad spacing on an FR4 board, using 10 mm − by − 1inch, 2 ounce copper trace no air flow per JESD51−7.
3. HBM tested to EIA / JESD22−A114−A. CDM tested to JESD22−C101−A. JEDEC recommends that ESD qualification to EIA/JESD22−A115A (Machine Model) be discontinued.
4. Tested to EIA/JESD78 Class II.

Table 2. RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Max	Unit
V_{CC}	Positive DC Supply Voltage		0.9	3.6	V
V_{IN}	Digital Input Voltage		0	3.6	V
V_{OUT}	Output Voltage	Active Mode (High or Low State) Tri−State Mode (Note 1) Power Down Mode (V_{CC} = 0 V)	0 0 0	V_{CC} 3.6 3.6	V
T_A	Operating Free−Air Temperature		−55	+125	°C
t_r, t_f	Input Transition Rise or Fall Rate	V_{CC} = 3.3 V ± 0.3 V	0	10	nS/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

Table 3. DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = 25°C			T_A = −55°C to +125°C		Unit
				Min	Typ	Max	Min	Max	
V_{IH}	High−Level Input Voltage		0.9	–	V_{CC}	–	–	–	V
			1.1 to 1.3	0.7 x V_{CC}	–	–	0.7 x V_{CC}	–	
			1.4 to 1.6	0.65 x V_{CC}	–	–	0.65 x V_{CC}	–	
			1.65 to 1.95	0.65 x V_{CC}	–	–	0.65 x V_{CC}	–	
			2.3 to 2.7	1.7	–	–	1.7	–	
			3.0 to 3.6	2.0	–	–	2.0	–	
V_{IL}	Low−Level Input Voltage		0.9	–	GND	–	–	–	V
			1.1 to 1.3	–	–	0.3 x V_{CC}	–	0.3 x V_{CC}	
			1.4 to 1.6	–	–	0.35 x V_{CC}	–	0.35 x V_{CC}	
			1.65 to 1.95	–	–	0.35 x V_{CC}	–	0.35 x V_{CC}	
			2.3 to 2.7	–	–	0.7	–	0.7	
			3.0 to 3.6	–	–	0.8	–	0.8	
V_{OH}	High−Level Output Voltage	V_{IN} = V_{IH} or V_{IL}							V
		I_{OH} = −20 μA	0.9	–	0.75	–	–	–	
		I_{OH} = −0.3 mA	1.1 to 1.3	0.75 x V_{CC}	–	–	0.75 x V_{CC}	–	
		I_{OH} = −1.7 mA	1.4 to 1.6	0.75 x V_{CC}	–	–	0.75 x V_{CC}	–	
		I_{OH} = −3.0 mA	1.65 to 1.95	V_{CC} − 0.45	–	–	V_{CC} − 0.45	–	
		I_{OH} = −4.0 mA	2.3 to 2.7	2.0	–	–	2.0	–	
		I_{OH} = −8.0 mA	3.0 to 3.6	2.48	–	–	2.48	–	
V_{OL}	Low−Level Output Voltage	V_{IN} = V_{IH} or V_{IL}							V
		I_{OL} = 20 μA	0.9	–	0.1	–	–	–	
		I_{OL} = 0.3 mA	1.1 to 1.3	–	–	0.25 x V_{CC}	–	0.25 x V_{CC}	
		I_{OL} = 1.7 mA	1.4 to 1.6	–	–	0.25 x V_{CC}	–	0.25 x V_{CC}	
		I_{OL} = 3.0 mA	1.65 to 1.95	–	–	0.45	–	0.45	
		I_{OL} = 4.0 mA	2.3 to 2.7	–	–	0.4	–	0.4	
		I_{OL} = 8.0 mA	2.7 to 3.6	–	–	0.4	–	0.4	
I_{IN}	Input Leakage Current	V_{IN} = 0 V to 3.6 V	0.9 to 3.6	–	–	±0.1	–	±1.0	μA
I_{OFF}	Power Off Leakage Current	V_{IN} = 0 V to 3.6 V; V_{OUT} = 0 V to 3.6 V	0	–	–	1.0	–	10.0	μA
I_{CC}	Quiescent Supply Current	V_{IN} = V_{CC} or GND	0.9 to 3.6	–	–	1.0	–	10.0	μA
I_{OZ}	3−State Output Leakage Current	V_{IN} = V_{IH} or V_{IL} V_{OUT} = 0 to 3.6V	0.9 to 3.6	–	–	1.0	–	10.0	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Table 4. AC ELECTRICAL CHARACTERISTICS

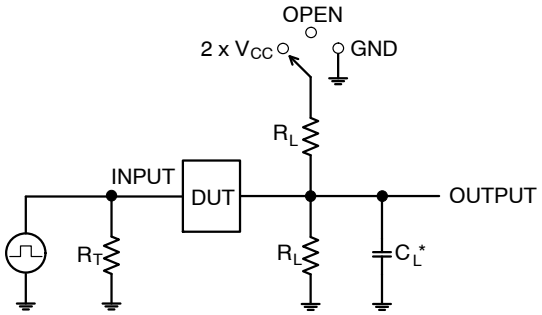
Symbol	Parameter	Test Condition	V_{CC} (V)	T_A = 25 °C			T_A = -55°C to +125°C		Unit
				Min	Typ	Max	Min	Max	
t_{PLH}, t_{PHL}	Propagation Delay, A to Y	C_L = 10 pF, R_L = 1 MΩ	0.9	-	44.4	–	-	–	ns
			1.1 to 1.3	-	10.8	29.2	-	33.9	
			1.4 to 1.6	-	5.0	8.5	-	10.0	
			1.65 to 1.95	-	4.0	6.2	-	6.7	
			2.3 to 2.7	-	2.6	3.9	-	4.4	
			3.0 to 3.6	-	2.1	3.1	-	3.7	
		C_L = 15 pF, R_L = 1 MΩ	0.9	-	44.9	–	-	–	ns
			1.1 to 1.3	-	11.0	29.9	-	34.7	
			1.4 to 1.6	-	5.6	9.3	-	11.2	
			1.65 to 1.95	-	4.5	6.9	-	7.1	
			2.3 to 2.7	-	2.9	4.4	-	5.0	
			3.0 to 3.6	-	2.4	3.4	-	3.9	
		C_L = 30 pF, R_L = 1 MΩ	0.9	-	46.2	–	-	–	ns
			1.1 to 1.3	-	11.6	32.0	-	37.1	
			1.4 to 1.6	-	8.2	13.1	-	15.9	
			1.65 to 1.95	-	6	9.2	-	9.6	
			2.3 to 2.7	-	4	5.7	-	6.1	
			3.0 to 3.6	-	3.3	4.4	-	4.8	
t_{PZH}, t_{PZL}	Output Enable Time, $\overline{OE}$ to Y	C_L = 10 pF;							ns
		R_L = 100 kΩ	0.9	-	43.3	–	-	–	
		R_L = 5 kΩ	1.1 to 1.3	-	10.5	29.0	-	33.7	
		R_L = 5 kΩ	1.4 to 1.6	-	5.3	7.8	-	8.3	
		R_L = 5 kΩ	1.65 to 1.95	-	3.9	5.5	-	5.9	
		R_L = 5 kΩ	2.3 to 2.7	-	2.5	3.5	-	3.8	
		R_L = 5 kΩ	3.0 to 3.6	-	2.1	2.7	-	3	
		C_L = 15 pF;							ns
		R_L = 100 kΩ	0.9	-	43.8	–	-	–	
		R_L = 5 kΩ	1.1 to 1.3	-	10.7	29.7	-	34.5	
		R_L = 5 kΩ	1.4 to 1.6	-	5.9	8.9	-	11	
		R_L = 5 kΩ	1.65 to 1.95	-	4.4	6.3	-	6.5	
		R_L = 5 kΩ	2.3 to 2.7	-	2.9	3.9	-	4.2	
		R_L = 5 kΩ	3.0 to 3.6	-	2.3	3	-	3.3	
		C_L = 30 pF;							ns
		R_L = 100 kΩ	0.9	-	45.1	–	-	–	
		R_L = 5 kΩ	1.1 to 1.3	-	11.2	31.8	-	36.9	
		R_L = 5 kΩ	1.4 to 1.6	-	8.3	12.2	-	13.7	
		R_L = 5 kΩ	1.65 to 1.95	-	6.1	8.6	-	9.7	
		R_L = 5 kΩ	2.3 to 2.7	-	3.8	5	-	5.5	
		R_L = 5 kΩ	3.0 to 3.6	-	2.9	3.8	-	4.2	

Table 4. AC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Condition	V_{CC} (V)	T_A = 25 °C			T_A = -55°C to +125°C		Unit
				Min	Typ	Max	Min	Max	
t_{PHZ}, t_{PLZ}	Output Disable Time, $\overline{OE}$ to Y	C_L = 10 pF;							ns
		R_L = 100 kΩ	0.9	-	89.6	-	-	-	
		R_L = 5 kΩ	1.1 to 1.3	-	9.1	16.5	-	22.4	
		R_L = 5 kΩ	1.4 to 1.6	-	7.1	9.1	-	10.4	
		R_L = 5 kΩ	1.65 to 1.95	-	6.5	8.3	-	9	
		R_L = 5 kΩ	2.3 to 2.7	-	5.8	7.3	-	8.8	
		R_L = 5 kΩ	3.0 to 3.6	-	5.4	10.1	-	10.3	
		C_L = 15 pF;							ns
		R_L = 100 kΩ	0.9	-	117.8	-	-	-	
		R_L = 5 kΩ	1.1 to 1.3	-	9.8	18.4	-	25.1	
		R_L = 5 kΩ	1.4 to 1.6	-	7.8	9.8	-	11.3	
		R_L = 5 kΩ	1.65 to 1.95	-	7.2	9.2	-	10.6	
		R_L = 5 kΩ	2.3 to 2.7	-	7	8.2	-	10.3	
		R_L = 5 kΩ	3.0 to 3.6	-	6.6	11.1	-	11.3	
		C_L = 30 pF;							ns
		R_L = 100 kΩ	0.9	-	202.1	-	-	-	
		R_L = 5 kΩ	1.1 to 1.3	-	13.2	24.3	-	31.9	
		R_L = 5 kΩ	1.4 to 1.6	-	12.2	13.5	-	14.9	
		R_L = 5 kΩ	1.65 to 1.95	-	11.4	12.7	-	13.9	
		R_L = 5 kΩ	2.3 to 2.7	-	11.3	12.2	-	13.5	
		R_L = 5 kΩ	3.0 to 3.6	-	10.2	14.8	-	15.1	
C_{IN}	Input Capacitance		0 to 3.6		3	-	-	-	pF
C_O	Output Capacitance	V_O = GND	0		3	-	-	-	pF
C_{PD}	Power Dissipation Capacitance (Note 5)	f = 10 MHz	0.9 to 3.6	-	4	-	-	-	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

5. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$. C_{PD} is used to determine the no−load dynamic power consumption; $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$.



Test	Switch Position
t_{PLH} / t_{PHL}	Open
t_{PLZ} / t_{PZL}	2 x V_{CC}
t_{PHZ} / t_{PZH}	GND

C_L includes probe and jig capacitance
R_T is Z_{OUT} of pulse generator (typically 50 W)
f = 1 MHz

Figure 5. Test Circuit

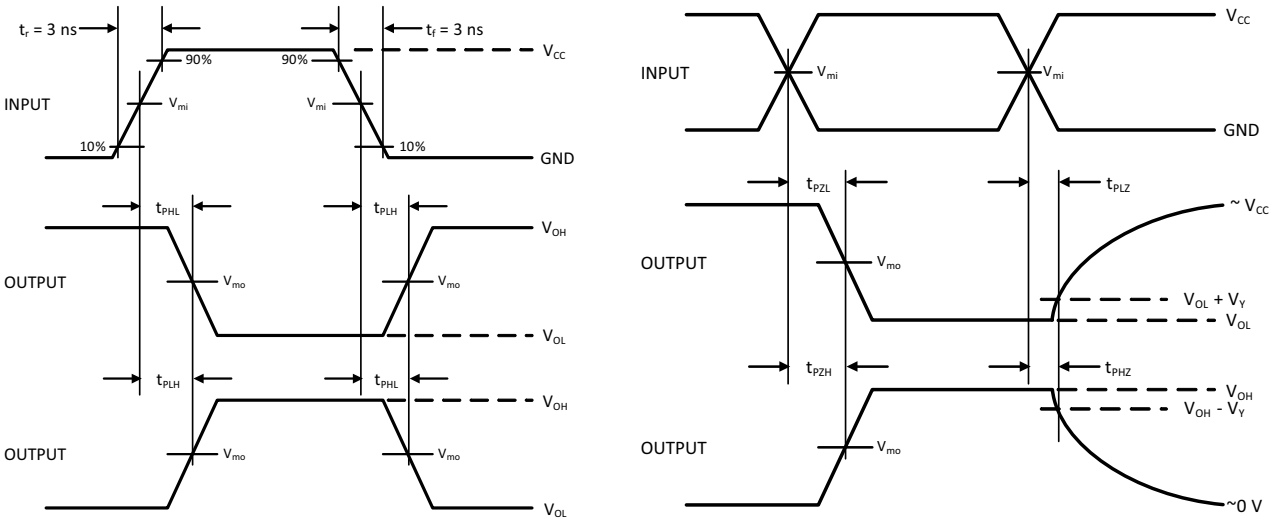


Figure 6. Switching Waveforms

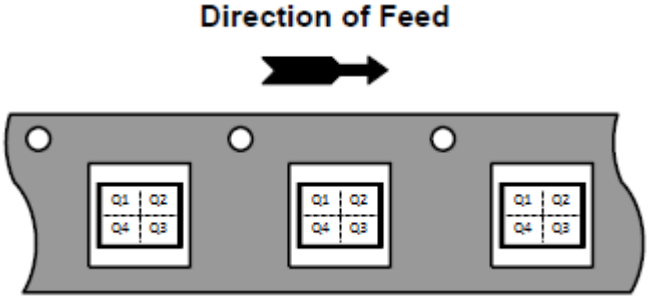
V_{CC}, V	V_{mi}, V	V_{mo}, V	V_Y, V
0.9	V_{CC}/2	V_{CC}/2	0.1
1.1 to 1.3	V_{CC}/2	V_{CC}/2	0.1
1.4 to 1.6	V_{CC}/2	V_{CC}/2	0.1
1.65 to 1.95	V_{CC}/2	V_{CC}/2	0.15
2.3 to 2.7	V_{CC}/2	V_{CC}/2	0.15
3.0 to 3.6	1.5	1.5	0.3

ORDERING INFORMATION

Device	Marking	Pin 1 Orientation (See below)	Package	Shipping†
NL17SG125DFT2G	A4	Q4	SC−88A	3000 / Tape & Reel
NL17SG125P5T5G	F (Rotated 90°CW)	Q2	SOT−953	8000 / Tape & Reel
NL17SG125MU1TCG (Contact **onsemi**)	TBD	Q4	UDFN6 1.45 x 1 mm	3000 / Tape & Reel
NL17SG125MU3TCG (Contact **onsemi**)	TBD	Q4	UDFN6 1 x 1 mm	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*−Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q101 Qualified and PPAP Capable.

PIN 1 ORIENTATION IN TAPE AND REEL



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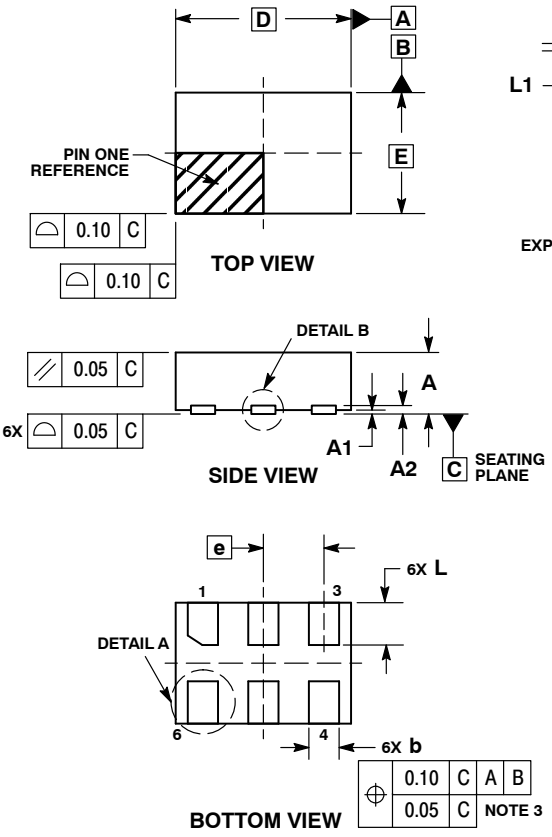
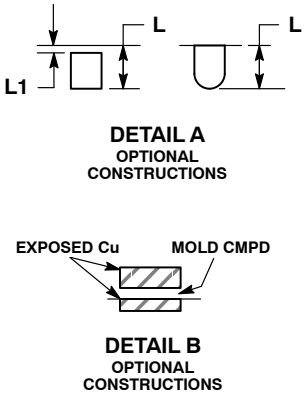
PACKAGE DIMENSIONS

UDFN6, 1.45x1.0, 0.5P
CASE 517AQ
ISSUE O

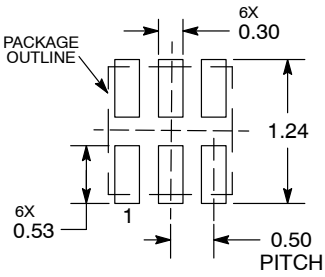




NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM THE TERMINAL TIP.

	MILLIMETERS	
DIM	MIN	MAX
A	0.45	0.55
A1	0.00	0.05
A2	0.07 REF	
b	0.20	0.30
D	1.45 BSC	
E	1.00 BSC	
e	0.50 BSC	
L	0.30	0.40
L1	---	0.15

MOUNTING FOOTPRINT

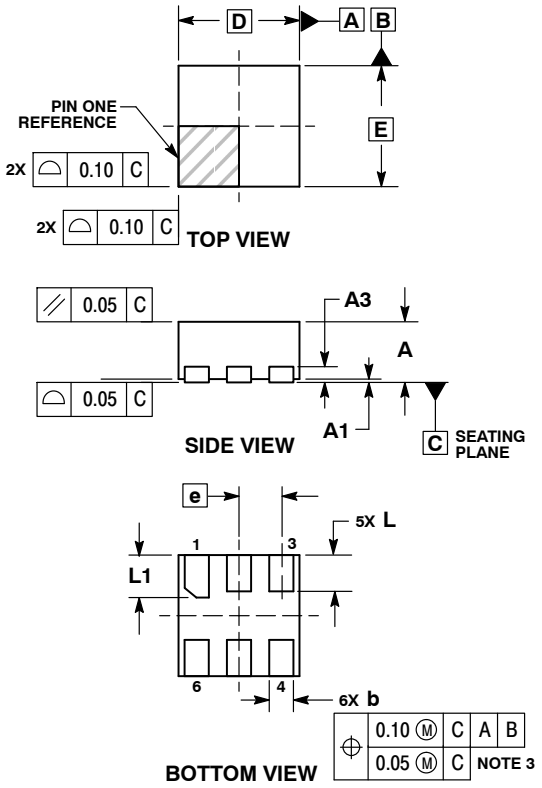


DIMENSIONS: MILLIMETERS

*For additional information on our Pb−Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

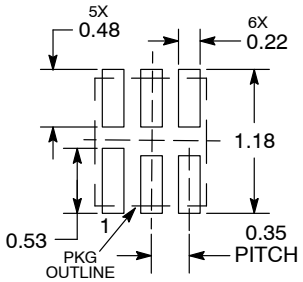
UDFN6, 1x1, 0.35P
CASE 517BX
ISSUE O



NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
4. PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

	MILLIMETERS	
DIM	MIN	MAX
A	0.45	0.55
A1	0.00	0.05
A3	0.13 REF	
b	0.12	0.22
D	1.00 BSC	
E	1.00 BSC	
e	0.35 BSC	
L	0.25	0.35
L1	0.30	0.40

RECOMMENDED SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

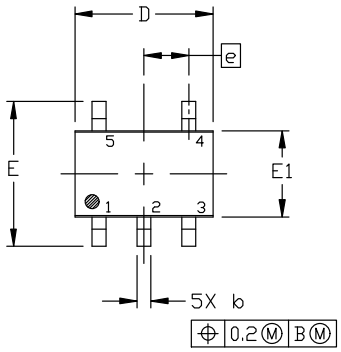
*For additional information on our Pb−Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

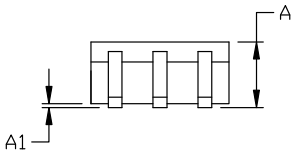
MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

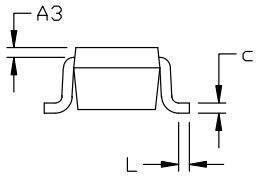
SCALE 2:1

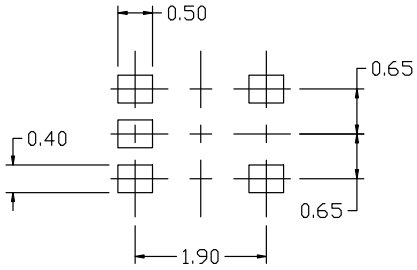
SC−88A (SC−70−5/SOT−353)
CASE 419A−02
ISSUE M

DATE 11 APR 2023









RECOMMENDED
MOUNTING FOOTPRINT

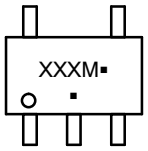
* For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS
3. 419A−01 OBSOLETE. NEW STANDARD 419A−02
4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.80	0.95	1.10
A1	---	---	0.10
A3	0.20 REF		
b	0.10	0.20	0.30
c	0.10	---	0.25
D	1.80	2.00	2.20
E	2.00	2.10	2.20
E1	1.15	1.25	1.35
e	0.65 BSC		
L	0.10	0.15	0.30

GENERIC MARKING DIAGRAM*



*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code
M = Date Code
▪ = Pb−Free Package

(Note: Microdot may be in either location)

STYLE 1:
PIN 1. BASE
2. EMITTER
3. BASE
4. COLLECTOR
5. COLLECTOR

STYLE 2:
PIN 1. ANODE
2. EMITTER
3. BASE
4. COLLECTOR
5. CATHODE

STYLE 3:
PIN 1. ANODE 1
2. N/C
3. ANODE 2
4. CATHODE 2
5. CATHODE 1

STYLE 4:
PIN 1. SOURCE 1
2. DRAIN 1/2
3. SOURCE 1
4. GATE 1
5. GATE 2

STYLE 5:
PIN 1. CATHODE
2. COMMON ANODE
3. CATHODE 2
4. CATHODE 3
5. CATHODE 4

STYLE 6:
PIN 1. EMITTER 2
2. BASE 2
3. EMITTER 1
4. COLLECTOR
5. COLLECTOR 2/BASE 1

STYLE 7:
PIN 1. BASE
2. EMITTER
3. BASE
4. COLLECTOR
5. COLLECTOR

STYLE 8:
PIN 1. CATHODE
2. COLLECTOR
3. N/C
4. BASE
5. EMITTER

STYLE 9:
PIN 1. ANODE
2. CATHODE
3. ANODE
4. ANODE
5. ANODE

Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

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DESCRIPTION:	SC−88A (SC−70−5/SOT−353)	PAGE 1 OF 1

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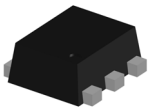
MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

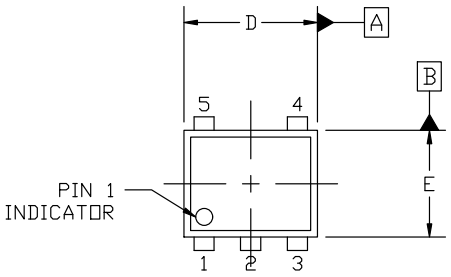


SOT−953 1.00x0.80x0.37, 0.35P
CASE 527AE
ISSUE F

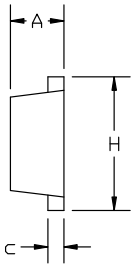
DATE 17 JAN 2024

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

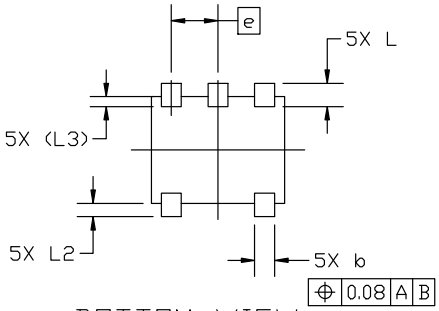
MILLIMETERS			
DIM	MIN	NOM	MAX
A	0.34	0.37	0.40
b	0.10	0.15	0.20
C	0.07	0.12	0.17
D	0.95	1.00	1.05
E	0.75	0.80	0.85
e	0.35 BSC		
H	0.95	1.00	1.05
L	0.125	0.175	0.225
L2	0.05	0.10	0.15
L3	0.075 (REF)		



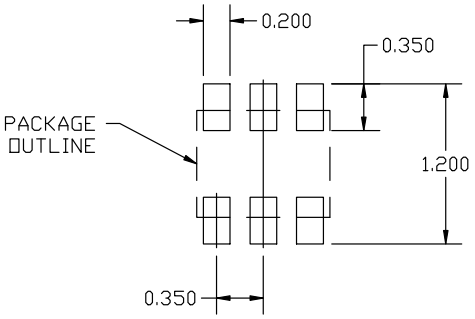
TOP VIEW



SIDE VIEW



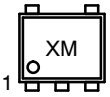
BOTTOM VIEW



RECOMMENDED MOUNTING FOOTPRINT

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



X = Specific Device Code
M = Month Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

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